



# DFB laser diodes from 1650 nm to 1850 nm

## nanoplus single mode laser diodes

nanoplus is the only manufacturer world-wide routinely providing single and multi mode lasers at any wavelength from 760 to 6000 nm. At wavelengths up to 14  $\mu\text{m}$ , QCLs complete nanoplus' laser portfolio. Our patented distributed feedback laser diodes deliver single mode emission with well defined optical properties enabling a wide range of applications.

nanoplus lasers operate reliably in tens of thousands of installations worldwide, including chemical and metallurgical industries, gas pipelines, power plants, medical systems, airborne and satellite applications.

### key features

- ✓ very high spectral purity
- ✓ narrow linewidth typically < 3 MHz
- ✓ excellent reliability
- ✓ wide variety of packaging options
- ✓ customer-specific designs available



### application areas

- ✓ high performance gas sensing for process and environmental control
- ✓ precision metrology
- ✓ atomic clocks
- ✓ spectroscopy
- ✓ space technology

nanoplus lasers with excellent performance are specifically designed and characterized to fit your needs. This data sheet summarizes typical properties of nanoplus DFB lasers in the range from 1650 nm to 1850 nm range. In this wavelength range e.g. methane, nitric oxide and hydrogen chloride can be detected with high sensitivity. Overleaf data is given as an example for DFB lasers used for high sensitivity HCl sensing.

general ratings (T = 25 °C)	symbol	unit	typical
optical output power	$P_{\text{out}}$	mW	5
typical maximum operating voltage	$V_{\text{op}}$	V	2
forward current	$I_f$	mA	70
side mode suppression ratio (SMSR)		dB	> 35

On request, lasers with specifically optimized properties, such as higher output power, are available.

laser packaging options
TO5.6 header with or without cap
TO5 header with TEC and NTC
butterfly housing with SM or PM fiber

For dimensions and accessories, please see [www.nanoplus.us](http://www.nanoplus.us)  
Further packaging options are available on request.

760 - 830 nm
830 - 920 nm
920 - 1100 nm
1100 - 1300 nm
1300 - 1450 nm
1450 - 1650 nm
<b>1650 - 1850 nm</b>
1850 - 1900 nm
1900 - 2200 nm
2200 - 2600 nm
2600 - 2900 nm
2900 - 4000 nm
4000 - 4600 nm
4600 - 5300 nm
6000 - 14000 nm

device protected by  
US patent 6.671.306  
US patent 6.846.689  
EU patent EP0984535

nanoplus America, Inc.  
777 29th Street  
Suite 100  
Boulder, CO, 80303  
USA

phone: +1 - 720 - 453 - 2454  
email: [victor.perez@nanoplus.com](mailto:victor.perez@nanoplus.com)  
internet: [www.nanoplus.us](http://www.nanoplus.us)

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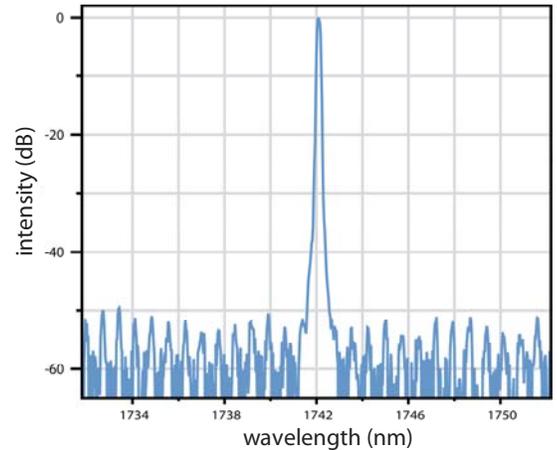
Rev. DFB1742.10.n+A



# nanoplus DFB laser diodes at 1742 nm

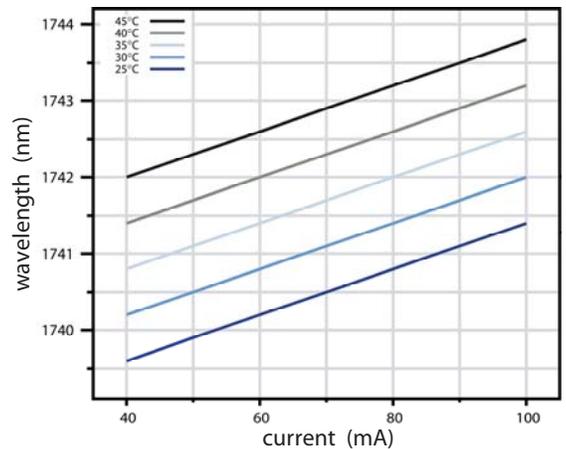
A wide variety of gas molecules exhibit characteristic absorption lines in the near infrared. DFB lasers emitting at 1742 nm are highly suited for sensitive detection of small HCl concentrations. For this application, highly stable laterally and longitudinally single mode lasers are required.

This data sheet reports performance data of nanoplus DFB lasers at this wavelength. Similar performance data are obtained in the entire wavelength range from 1650 nm to 1850 nm. For examples of performance data of nanoplus lasers in other wavelength ranges, please see [www.nanoplus.us](http://www.nanoplus.us) or contact [victor.perez@nanoplus.com](mailto:victor.perez@nanoplus.com)



**Fig. 1**  
Room temperature cw spectrum of a nanoplus DFB laser diode operating at 1742 nm

In many applications, temperature and/or current variations are used to adjust the laser emission precisely to the target wavelength.



**Fig. 2**  
Mode hop free tuning of 1742 nm based DFBs by current variation at different temperatures

electrooptical characteristics (T = 25 °C)	symbol	unit	min	typ	max
peak wavelength	$\lambda$	nm	1741	1742	1743
threshold current	$I_{th}$	mA	20	35	65
temperature tuning coefficient	$C_T$	nm / K	0.07	0.10	0.14
current tuning coefficient	$C_I$	nm / mA	0.008	0.02	0.03
slow axis (FWHM)		degrees	20	30	40
fast axis (FWHM)		degrees	40	50	60
emitting area	W x H	$\mu\text{m} \times \mu\text{m}$	2 x 1	3 x 1.5	5 x 2
storage temperatures	$T_s$	°C	- 40	+ 20	+ 80
operational temperature at case	$T_c$	°C	- 20	+ 25	+ 50



We will be happy to answer further questions. Please contact us at [victor.perez@nanoplus.com](mailto:victor.perez@nanoplus.com)